



#### HALF BRIDGE GATE DRIVER IN SO-8

#### Description

The DGD2184 is a high voltage / high speed gate driver capable of driving N-Channel MOSFETs and IGBTs in a half bridge configuration. High voltage processing techniques enable the DGD2184's high-side to switch to 600V in a bootstrap operation.

The DGD2184 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) for easy interfacing with controlling devices. The driver outputs feature high pulse current buffers designed for minimum driver cross conduction. The DGD2184 has a fixed internal deadtime of 395ns (typ).

The DGD2184 is offered in SO-8 package, the operating temperature extends from  $\ -40^\circ C$  to +125°C.

### **Applications**

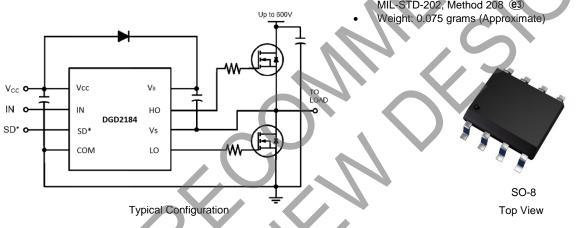
- DC-DC Converters
- DC-AC Inverters
- AC-DC Power Supplies
- Motor Controls
- Class D Power Amplifiers

#### Features

- Floating High-Side Driver in Bootstrap Operation to 600V
- Drives Two N-Channel MOSFETs or IGBTs in Half Bridge Configuration
- 1.4A Source / 1.8A Sink Output Current Capability
- Outputs Tolerant to Negative Transients
- Internal Dead Time of 395ns to Protect MOSFETs
- Wide Low-Side Gate Driver and Logic Supply: 10V to 20V
- Logic Input (IN and SD\*) 3.3V Capability
- Schmitt Triggered Logic Inputs with Internal Pull Down
- Undervoltage Lockout for High and Low Side Drivers
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic. "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (C)



#### Ordering Information (Note 4)

		-						
Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel				
DGD2184S8-13	DGD2184	13	12	2,500				
Notos: 1 No purposoly added load Eully EL Directive 2002/05/EC (PoHS) 2011/65/ELI (PoHS 2) & 2015/962/ELI (PoHS 2) compliant								

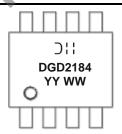
No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

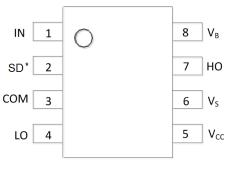
# Marking Information



Cli = Manufacturer's marking DGD2184 = Product Type Marking Code YY = Year (ex: 19 = 2019) WW = Week (01 to 53)



# Pin Diagrams

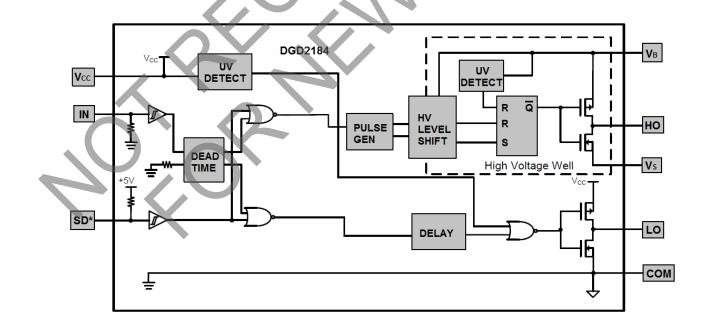


#### Top View: SO-8

### **Pin Descriptions**

Pin Number	Pin Name	Function
1	IN	Logic input for High-side and Low-side Gate Driver Outputs (HO and LO), in Phase with HO
2	SD*	Logic Input for Shutdown, Enabled Low
3	COM	Low-Side and Logic Return
4	LO	Low-Side Gate Drive Output
5	Vcc	Low-Side and Logic Fixed Supply
6	Vs	High-Side Floating Supply Return
7	HO	High-Side Gate Drive Output
8	VB	High-Side Floating Supply

# **Functional Block Diagram**





#### **NOT RECOMMENDED FOR NEW DESIGN -**USE DGD2184M

**DGD2184** 

### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
High-Side Floating Supply Voltage	VB	-0.3 to +624	V	
High-Side Floating Supply Offset Voltage	Vs	V <sub>B</sub> -24 to V <sub>B</sub> +0.3	V	
High-Side Floating Output Voltage	V <sub>HO</sub>	V <sub>S</sub> -0.3 to V <sub>B</sub> +0.3	V	
Offset Supply Voltage Transient	dV <sub>S</sub> / dt	50	V/ns	
Low-Side Fixed Supply Voltage	V <sub>CC</sub>	-0.3 to +24	V	
Low-Side Output Voltage	V <sub>LO</sub>	-0.3 to V <sub>CC</sub> +0.3	V	
Logic Input Voltage (IN and SD*)	V <sub>IN</sub>	-0.3 to V <sub>CC</sub> +0.3	V	

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear derating factor (Note 5)	PD	0.625	W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	200	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (Soldering, 10s)	TL	+300	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board.

# **Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
High-Side Floating Supply Absolute Voltage	VB	V <sub>S</sub> + 10	V <sub>S</sub> + 20	V
High-Side Floating Supply Offset Voltage	Vs	(Note 6)	600	V
High-Side Floating Output Voltage	V <sub>HO</sub>	Vs	VB	V
Low-Side Fixed Supply Voltage	Vcc	10	20	V
Low-Side Output Voltage	V <sub>LO</sub>	0	V <sub>CC</sub>	V
Logic Input Voltage (IN and SD*)	VIN	0	Vcc	V
Ambient Temperature	TA	-40	+125	°C

6. Logic operation for  $V_S$  of -5V to +600V. Note:





# **DC Electrical Characteristics** ( $V_{BIAS}$ ( $V_{CC}$ , $V_{BS}$ ) = 15V, @T<sub>A</sub> = +25°C, unless otherwise specified.) (Note 7)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions	
Logic "1" Input Voltage (Note 8)	VIH	2.5	—	-	V	$V_{CC}$ = 10V to 20V	
Logic "0" Input Voltage (Note 8)	VIL	-	-	0.8	V	$V_{CC} = 10V$ to 20V	
SD* Input Positive Going Threshold	V <sub>SDTH+</sub>	2.5	_	-	V	$V_{CC}$ = 10V to 20V	
SD* Input Negative Going Threshold	V <sub>SDTH-</sub>	_	-	0.8	V	$V_{CC} = 10V$ to 20V	
High Level Output Voltage, V <sub>BIAS</sub> - V <sub>O</sub>	Vон	-	-	1.2	V	$I_{O} = 0 m A$	
Low Level Output Voltage, Vo	V <sub>OL</sub>	_	-	0.1	V	$I_0 = 20 \text{mA}$	
Offset Supply Leakage Current	I <sub>LK</sub>	_	-	50	μA	$V_{B} = V_{S} = 600V$	
Quiescent V <sub>BS</sub> Supply Current	I <sub>BSQ</sub>	20	60	150	μA	$V_{IN} = 0V \text{ or } 5V$	
Quiescent V <sub>CC</sub> Supply Current	ICCQ	0.4	1.0	1.8	mA	$V_{IN} = 0V \text{ or } 5V$	
Logic "1" Input Bias Current	I <sub>IN+</sub>	-	25	60	μA	IN = 5V, SD* = 0V	
Logic "0" Input Bias Current	I <sub>IN-</sub>	-	_	1.0	μA	IN = 0V, SD* = 5V	
V <sub>BS</sub> Supply Under-Voltage Positive Going Threshold	V <sub>BSUV+</sub>	8.0	8.9	9.8	V	_	
V <sub>BS</sub> Supply Under- Voltage Negative Going Threshold	V <sub>BSUV-</sub>	7.4	8.2	9.0	V	-	
V <sub>CC</sub> Supply Under- Voltage Positive Going Threshold	V <sub>CCUV+</sub>	8.0	8.9	9.8	V	-	
V <sub>CC</sub> Supply Under-Voltage Negative Going Threshold	V <sub>CCUV</sub> -	7.4	8.2	9.0	V	-	
Output High Short Circuit Pulsed Current	I <sub>O+</sub>	1.4	1.9		А	V <sub>O</sub> = 0V, PW ≤ 10µs	
Output Low Short Circuit Pulsed Current	I <sub>0-</sub>	1.7	2.3	-	A	V <sub>O</sub> = 15V, PW ≤ 10µs	

Notes:

7. The V<sub>IN</sub>, and I<sub>IN</sub> parameters are applicable to the two logic input pins: IN and SD\*. The V<sub>O</sub> and I<sub>O</sub> parameters are applicable to the respective output pins: HO and LO.

 For optimal operation, it is recommended that the input pulses (IN and SD\*) should have an minimum amplitude of 2.5V with a minimum pulse width of 800ns.

### AC Electrical Characteristics (V<sub>BIAS</sub> (V<sub>CC</sub>, V<sub>BS</sub>) = 15V, C<sub>L</sub> = 1000pF, @T<sub>A</sub> = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-On Propagation Delay	t <sub>ON</sub>	Ŧ	680	900	ns	$V_{\rm S} = 0V$
Turn-Off Propagation Delay	tOFF	-	270	400	ns	$V_{\rm S} = 0V \text{ or } 600V$
Shutdown Propagation Delay	t <sub>SD</sub>		180	270	ns	-
Delay Matching, HO & LO Turn-On	t <sub>DMON</sub>		_	90	ns	-
Delay Matching, HO & LO Turn-Off	<b>t</b> DMOFF	Ŧ	-	40	ns	$I_0 = 0A$
Turn-On Rise Time	t <sub>R</sub>	_	40	60	ns	$V_{S} = 0V$
Turn-Off Fall Time	tF	_	20	35	ns	$V_{\rm S} = 0V$
Deadtime: t <sub>DT LO-HO &amp;</sub> t <sub>DT HO-LO</sub>	t <sub>DT</sub>	345	395	445	ns	-

DGD2184 Document Number: DS38285 Rev. 4 - 3



# **Timing Waveforms**

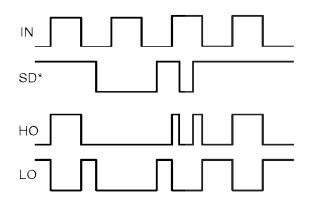


Figure 1. Input / Output Timing Diagram

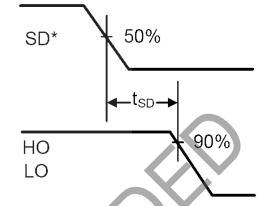
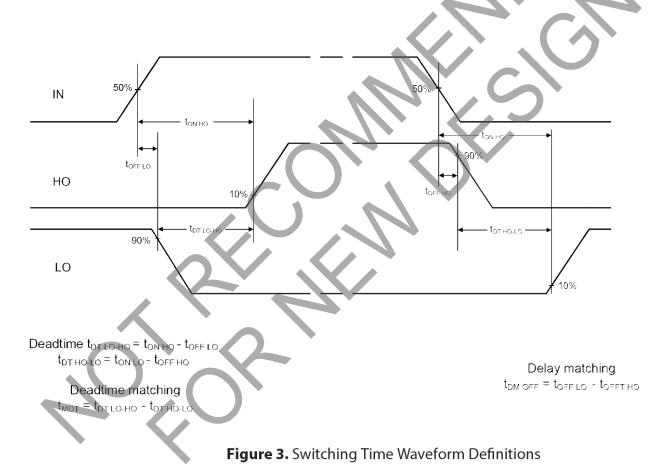
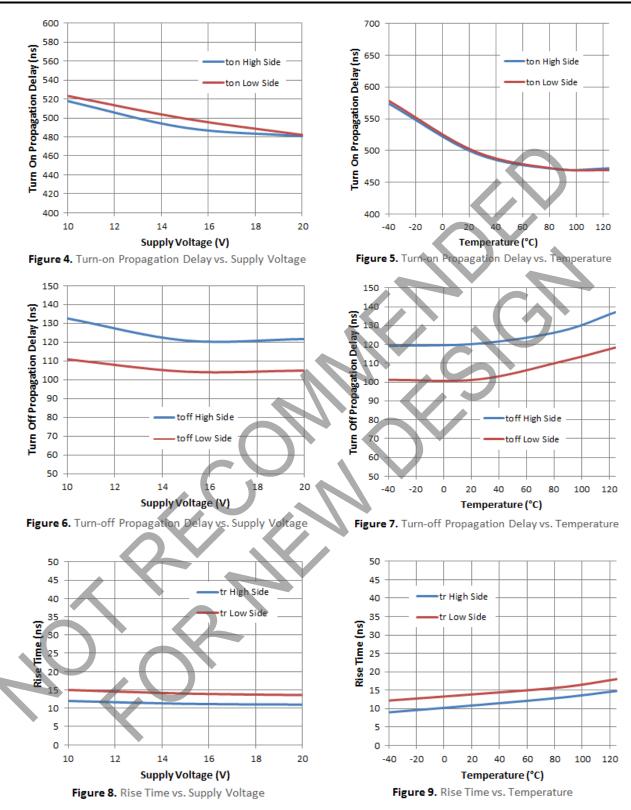


Figure 2. Shutdown Waveform Definitions

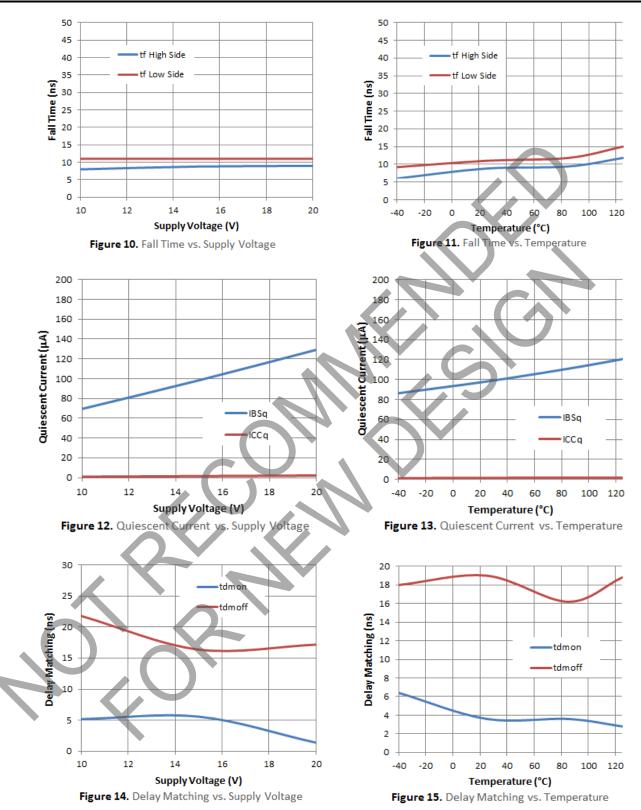




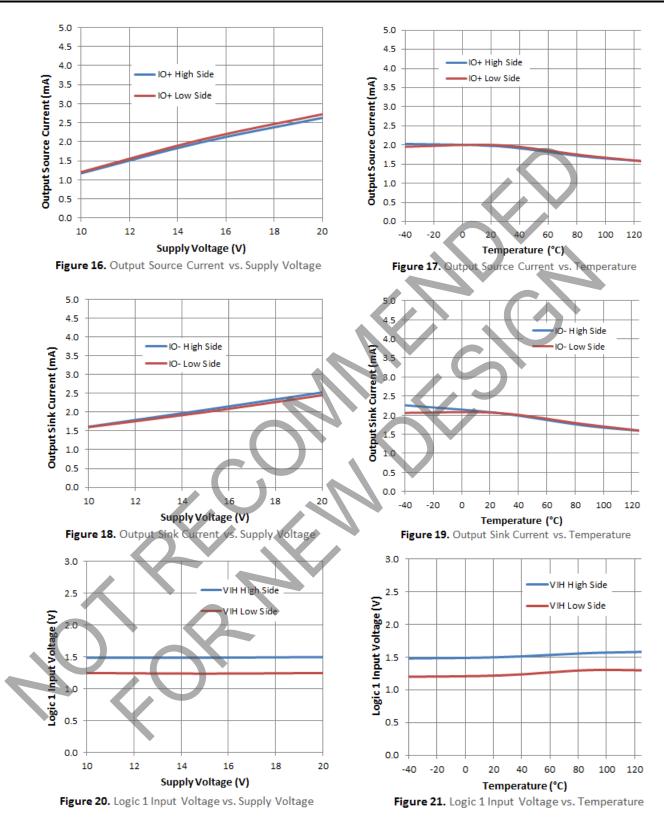
### Typical Performance Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



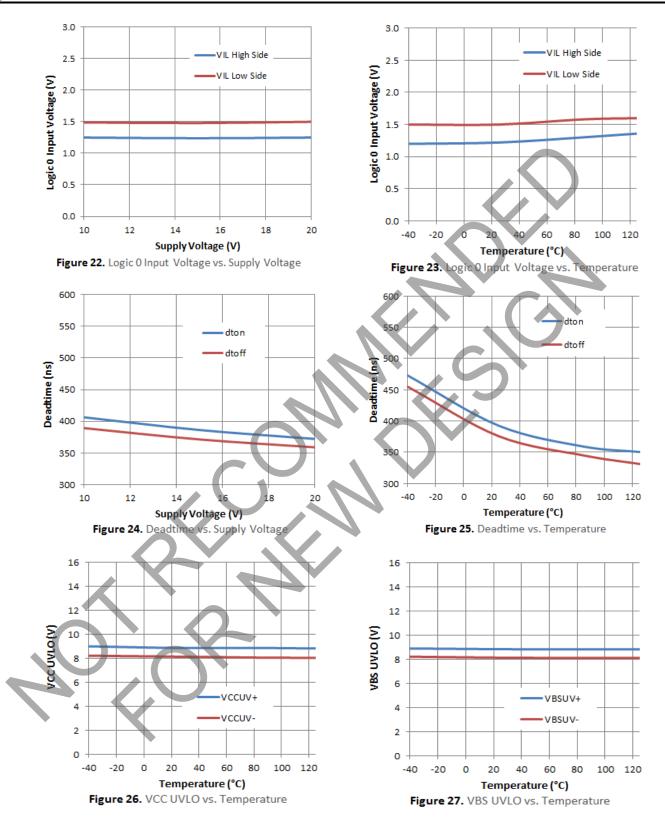














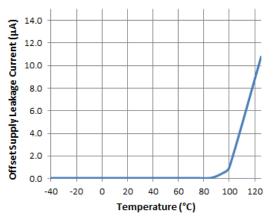
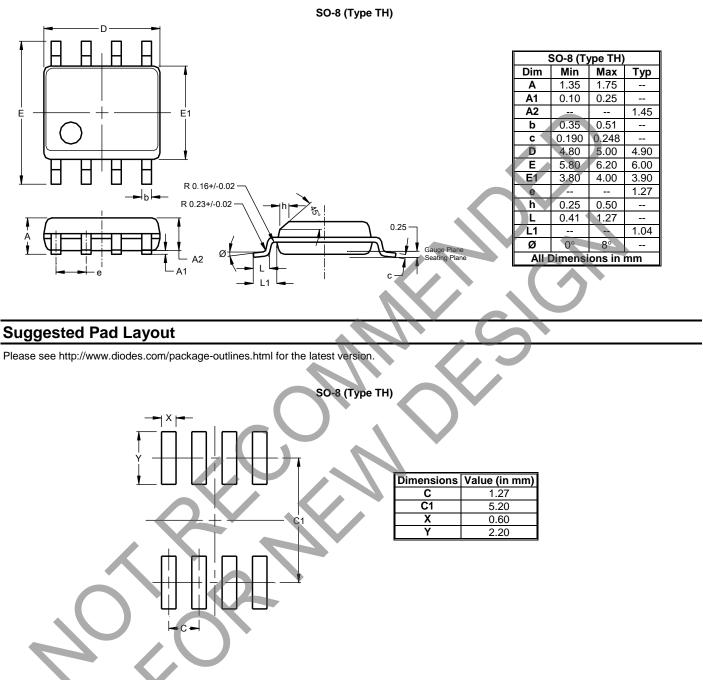


Figure 28. Offset Supply Leakage Current vs. Temperature



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Note:

: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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